

A Product Line of **Diodes Incorporated**

LITE-ON SEMICONDUCTOR **FUS1DE**

SURFACE MOUNT FAST RECOVERY RECTIFIERS

REVERSE VOLTAGE FORWARD CURRENT

- 200 Volts - 1.0 Ampers

F1A **FEATURES** Fast switching for high efficiency · For surface mounted applications F1A · Glass passivated chip DIM. MIN. TYP MAX. · Low reverse leakage current Li. 3.50 3.90 Low forward voltage drop А 3.80 High current capability В 1.70 1.90 2.00 • Qualified according to AEC-Q101 Rev C A С 0.81 1.20 1.18 Lead-Free Finish; RoHS Compliant (Notes 1 & 2) • Halogen and Antimony Free. "Green" Device (Note 3) D 2.70 2.80 2.90 1.35 Е 0.80 1.00 F 0.05 0.30 0.15 **MECHANICAL DATA** G 0.35 0.60 0.85 Package: JEDEC DO-219AA · Package Material: "Green" molding compound, UL Н 0.03 0.07 0.10 Flammability classification 94V-0, "Halogen-free". 0° 5° I 8° • Terminals: Lead Free Plating (Matte Tin Finish.) Component in accordance to RoHs 2002/95/EC All dimension in millimeter. Marking code: U1D Weight: 16.5 mg(Approximate) MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATING

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	200	V
Maximum DC blocking voltage		V _{DC}	200	V
Maximum Average rectified forward current	@Tc=90°C	I _(AV)	1.0	А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load		I _{FSM}	30	А
Operating and Storage temperature range		$T_{J,} T_{STG}$	-55 ~ +150	°C

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST C	ONDITION	SYMBOL	ТҮР	MAX	UNIT
Forward voltage	I _F =1.0A	T _J =25°C	VF		1.0	V
Leakage current	V _R =200V	T _J =25°C T _J =100°C	I _R		5 100	uA
Typical junction capacitance (Note 4)			CJ	20		pF

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	ТҮР	UNIT
	RthJ _A	100	
Typical Thermal Resistance (Note 5)	RthJ∟	45	°C/W
	RthJ _c	60	

DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MAX		UNIT
Reverse recovery time	I _F =0.5A ,I _{RR} =0.25A,I _R =1.0A	T _{RR}	50		nS
Note:				REV3, Oct-2021, I	(SEP10

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

antimony compounds. 4. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

5. Thermal resistance test performed in accordance with JESD-51.



1.2

RATING AND CHARACTERISTIC CURVES FUS1DE

FIG.1- FORWARD CURRENT DERATING CURVE

0.001 L 0

50

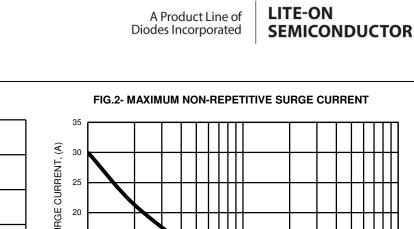
100

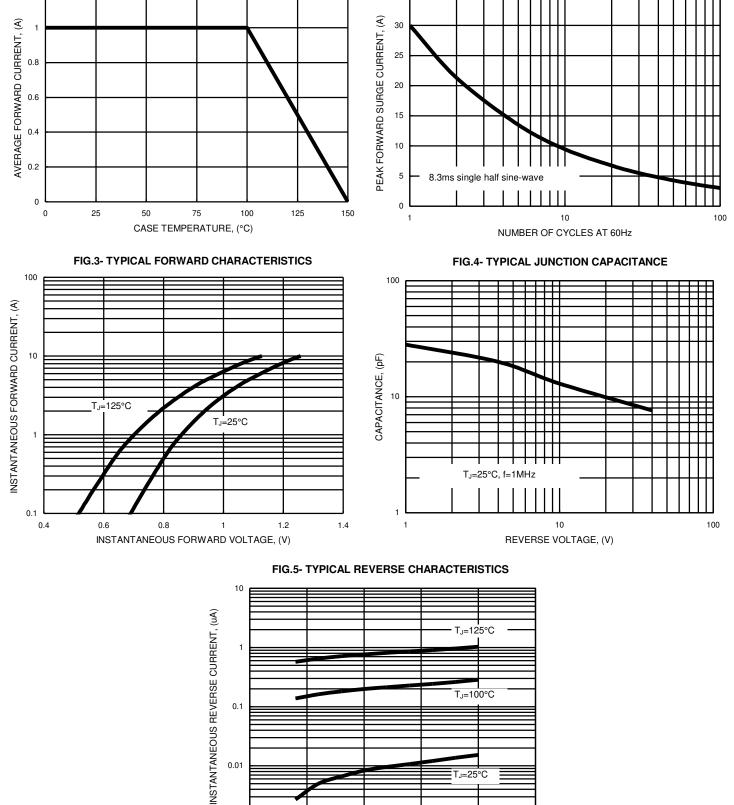
150

RATED PEAK REVERSE VOLTAGE, (V)

200

250





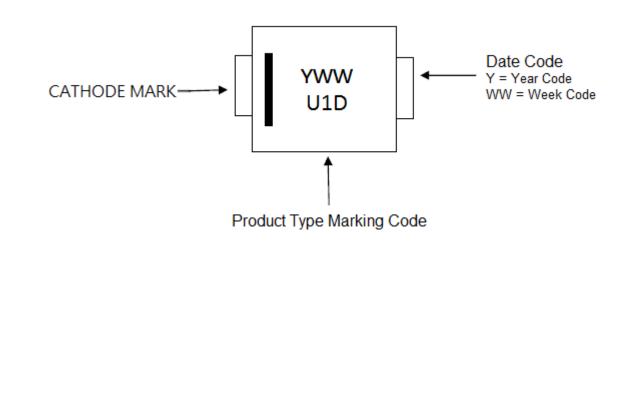


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Ordering Information :

Part Number	Dookogo	Packing		
	гаскауе	Package Qty.		
FUS1DE-7	F1A	2500	Tape & Reel	
FUS1DE	F1A	10000	Tape & Reel	

Marking Information :





LITE-ON SEMICONDUCTOR

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